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CSD23280F3

#### SLPS601 - APRIL 2016

# CSD23280F3 –12-V P-Channel FemtoFET™ MOSFET

Technical

Documents

#### 1 Features

- Low On Resistance
- Ultra-Low Q<sub>q</sub> and Q<sub>qd</sub>
- High Operating Drain Current
- Ultra-Small Footprint
  - 0.73 mm × 0.64 mm
- Ultra-Low Profile
- 0.35-mm Max Height
- Integrated ESD Protection Diode
  - Rated > 4-kV HBM
  - Rated > 2-kV CDM
- Lead and Halogen Free
- RoHS Compliant

#### 2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching Applications
- Battery Applications
- Handheld and Mobile Applications

#### 3 Description

This -12-V, 97-m $\Omega$ , P-Channel FemtoFET<sup>TM</sup> MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing a substantial reduction in footprint size.

#### **Product Summary**

Support &

Community

20

Tools &

Software

T <sub>A</sub> = 25°	C	TYPICAL VA	UNIT	
V <sub>DS</sub>	Drain-to-Source Voltage	-12		V
Qg	Gate Charge Total (4.5 V)	0.95		nC
Q <sub>gd</sub>	Gate Charge Gate-to-Drain	0.068	nC	
		$V_{GS} = -1.5 V$	230	mΩ
Р	Drain-to-Source	$V_{GS} = -1.8 V$	180	mΩ
R <sub>DS(on)</sub>	On-Resistance	$V_{GS} = -2.5 V$	129	mΩ
		$V_{GS} = -4.5 V$	97	mΩ
V <sub>GS(th)</sub>	Threshold Voltage	-0.65	V	

#### Ordering Information<sup>(1)</sup>

DEVICE	QTY	MEDIA	PACKAGE	SHIP								
CSD23280F3	3000		Femto	Tape								
CSD23280F3T	250	7-Inch Reel	0.73-mm × 0.64-mm Land Grid Array (LGA)	and Reel								

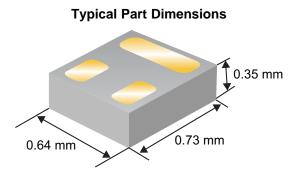
(1) For all available packages, see the orderable addendum at the end of the data sheet.

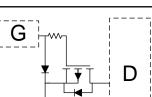
#### Absolute Maximum Ratings

T <sub>A</sub> = 25	°C	VALUE	UNIT
V <sub>DS</sub>	Drain-to-Source Voltage	-12	V
$V_{GS}$	Gate-to-Source Voltage	-6	V
I <sub>D</sub>	Continuous Drain Current <sup>(1)</sup>	1.8	А
I <sub>DM</sub>	Pulsed Drain Current <sup>(1)(2)</sup>	11.4	А
PD	Power Dissipation <sup>(1)</sup>	500	mW
V	Human Body Model (HBM)	4000	V
V (ESD)	Charged Device Model (CDM)	2000	V
T <sub>J</sub> , T <sub>stg</sub>	Operating Junction, Storage Temperature	-55 to 150	°C

(1) Typical  $R_{\theta JA}$  = 255°C/W on 1-in² (6.45-cm²), 2-oz. (0.071-mm) thick Cu pad on a 0.06-in (1.52-mm) thick FR4 PCB.

(2) Pulse duration  $\leq$  100 µs, duty cycle  $\leq$  1%





## Top View

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



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### **4** Revision History

DATE	REVISION	NOTES
April 2016	*	Initial release.

## **5** Specifications

#### 5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$  (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS				P	
BV <sub>DSS</sub>	Drain-to-source voltage	$V_{GS} = 0 V, I_{DS} = -250 \mu A$	-12			V
I <sub>DSS</sub>	Drain-to-source leakage current	$V_{GS} = 0 V, V_{DS} = -9.6 V$			-50	nA
I <sub>GSS</sub>	Gate-to-source leakage current	$V_{DS} = 0 V, V_{GS} = -5 V$			-25	nA
V <sub>GS(th)</sub>	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_{DS} = -250 \ \mu A$	-0.40	-0.65	-0.95	V
		$V_{GS} = -1.5 \text{ V}, \text{ I}_{DS} = -0.1 \text{ A}$		230	399	mΩ
D		$V_{GS} = -1.8 \text{ V}, \text{ I}_{DS} = -0.4 \text{ A}$		180	250	mΩ
R <sub>DS(on)</sub>	Drain-to-source on-resistance	$V_{GS} = -2.5 \text{ V}, \text{ I}_{DS} = -0.4 \text{ A}$		129	165	mΩ
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{DS} = -0.4 \text{ A}$		97	116	mΩ
<b>g</b> <sub>fs</sub>	Transconductance	$V_{DS} = -1.2 \text{ V}, \text{ I}_{DS} = -0.4 \text{ A}$		3		S
DYNAMI	C CHARACTERISTICS				Ľ	
C <sub>iss</sub>	Input capacitance			180	234	pF
C <sub>oss</sub>	Output capacitance	$V_{GS} = 0 V, V_{DS} = -6 V,$ f = 1 MHz		73	95	pF
C <sub>rss</sub>	Reverse transfer Capacitance	) = 1 Wi 12		8.5	11.1	pF
R <sub>G</sub>	Series gate resistance			9		Ω
Qg	Gate charge total (4.5 V)			0.95	1.23	nC
Q <sub>gd</sub>	Gate charge gate-to-drain			0.068		nC
Q <sub>gs</sub>	Gate charge gate-to-source	$V_{\rm DS} = -6$ V, $I_{\rm DS} = -0.4$ A		0.30		nC
Q <sub>g(th)</sub>	Gate charge at V <sub>th</sub>			0.15		nC
Q <sub>oss</sub>	Output charge	$V_{DS} = -6 V, V_{GS} = 0 V$		1.07		nC
t <sub>d(on)</sub>	Turn on delay time			8		ns
t <sub>r</sub>	Rise time	$V_{DS} = -6 V, V_{GS} = -4.5 V,$		4		ns
t <sub>d(off)</sub>	Turn off delay time	$I_{DS} = -0.4 \text{ A}, \text{ R}_{G} = 0 \Omega$		21		ns
t <sub>f</sub>	Fall time			8		ns
DIODE C	CHARACTERISTICS				Ľ	
V <sub>SD</sub>	Diode forward voltage	I <sub>SD</sub> = -0.4 A, V <sub>GS</sub> = 0 V		-0.73	-1.0	V

## 5.2 Thermal Information

 $T_A = 25^{\circ}C$  (unless otherwise stated)

		THERMAL METRIC	TYPICAL VALUES	UNIT
-		Junction-to-ambient thermal resistance <sup>(1)</sup>	90	°C/W
F	R <sub>0JA</sub>	Junction-to-ambient thermal resistance <sup>(2)</sup>	255	°C/W

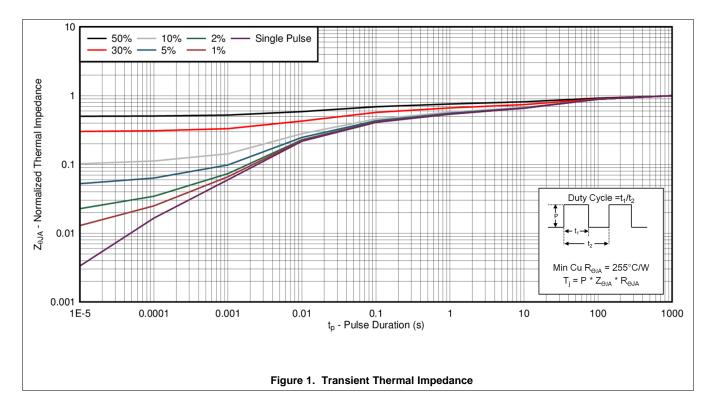
Device mounted on FR4 material with 1-in<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm) thick Cu.
 Device mounted on FR4 material with minimum Cu mounting area.

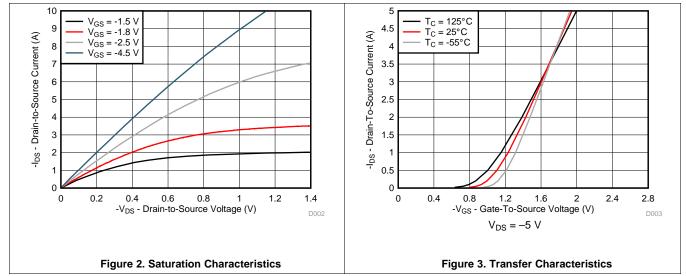
# CSD23280F3

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## 5.3 Typical MOSFET Characteristics

 $T_A = 25^{\circ}C$  (unless otherwise stated)





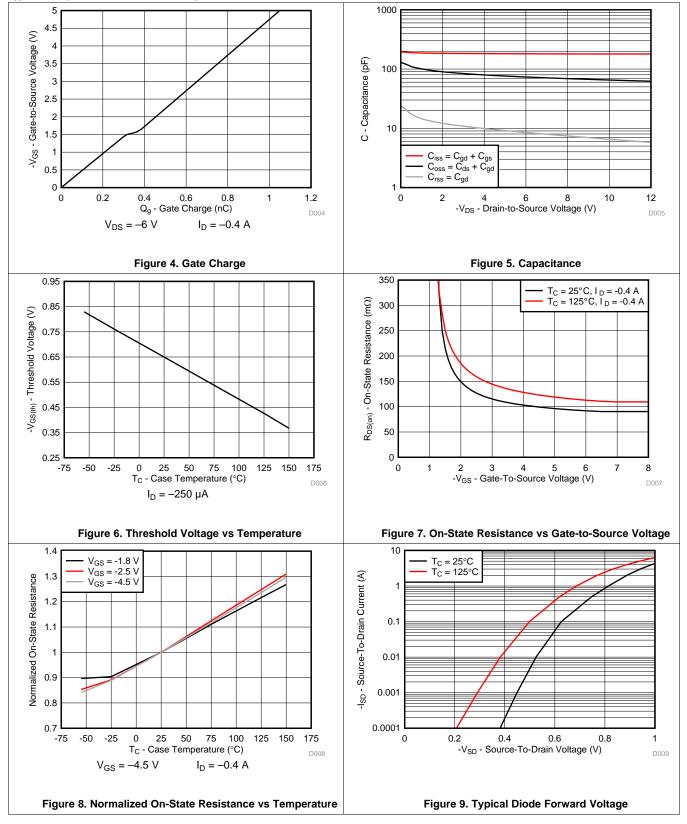


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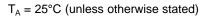
#### **Typical MOSFET Characteristics (continued)**

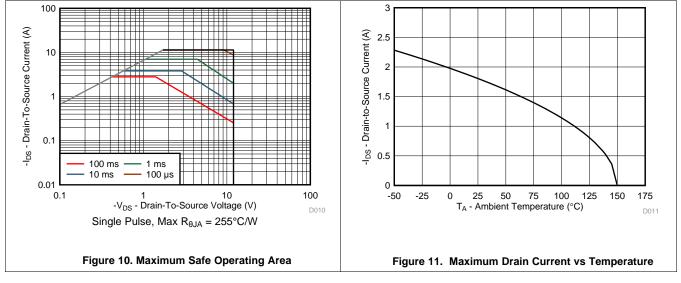
 $T_A = 25^{\circ}C$  (unless otherwise stated)





## **Typical MOSFET Characteristics (continued)**







#### 6 Device and Documentation Support

#### 6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 6.2 Trademarks

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#### 6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 6.4 Glossary

SLYZ022 — TI Glossary.

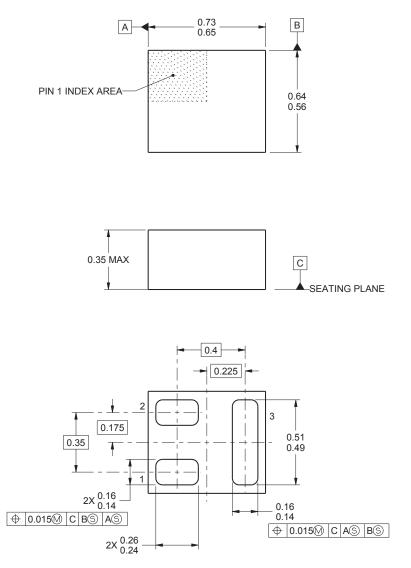
This glossary lists and explains terms, acronyms, and definitions.



#### Mechanical, Packaging, and Orderable Information 7

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

#### Mechanical Dimensions 7.1



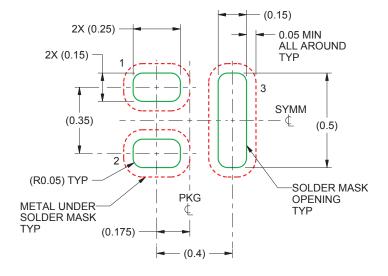
- (1) All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
- This drawing is subject to change without notice. (2)
- (3) This package is a PB-free solder land design.

Pin Configuration								
Position	Designation							
Pin 1	Gate							
Pin 2	Source							
Pin 3	Drain							

## ---

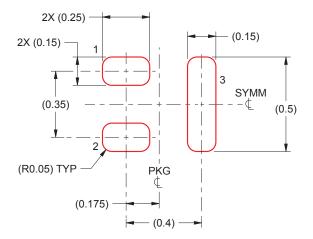


#### 7.2 Recommended Minimum PCB Layout



(1) All dimensions are in millimeters.

#### 7.3 Recommended Stencil Pattern



(1) All dimensions are in millimeters.



20-May-2016

# PACKAGING INFORMATION

	Orderable Device		Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
-		(1)		U			(2)	(6)	(3)		(4/5)	
	CSD23280F3	ACTIVE	PICOSTAR	YJM	3	3000	Green (RoHS	Call TI	Level-1-260C-UNLIM	-55 to 150	5	Samples
							& no Sb/Br)					Samples
	CSD23280F3T	ACTIVE	PICOSTAR	YJM	3	250	Green (RoHS	Call TI	Level-1-260C-UNLIM	-55 to 150	5	Same las
							& no Sb/Br)					Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE OPTION ADDENDUM

20-May-2016

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# PACKAGE MATERIALS INFORMATION

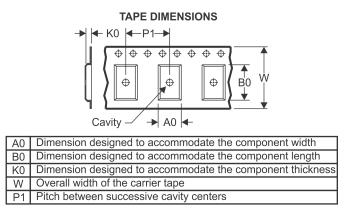
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#### TAPE AND REEL INFORMATION



\*All dimensions are nominal



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD23280F3	PICOST AR	YJM	3	3000	180.0	8.4	0.7	0.79	0.44	4.0	8.0	Q2
CSD23280F3	PICOST AR	YJM	3	3000	178.0	8.4	0.7	0.79	0.44	4.0	8.0	Q2

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

9-Jul-2016



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD23280F3	PICOSTAR	YJM	3	3000	182.0	182.0	20.0
CSD23280F3	PICOSTAR	YJM	3	3000	220.0	220.0	35.0

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